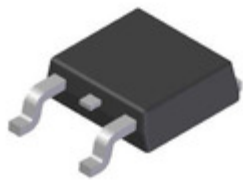




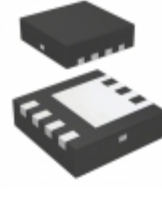





	DMG4800LK3-13	
	Hersteller-Teilenummer:	DMG4800LK3-13
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET N-CH 30V 10A TO252
	Datenblätter:	 DMG4800LK3-13.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 35714 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	DMG4800LK3-13
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CH 30V 10A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	35714 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252-3
Verlustleistung (max)	1.71W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Ta)
Rds On (Max) @ Id, Vgs	17 mOhm @ 9A, 10V
VGS (th) (Max) @ Id	1.6V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.7nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	798pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































DMG4800LK3-13 ist neu im Original, Suche DMG4800LK3-13 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMG4800LK3-13 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMG4800LK3-13: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>DMG4712SSS D DMG4712SSS D</p>	 <p>DMG4800LSD DIODES DMG4800LSD DIODES</p>	 <p>DMG4800LFG-7 Diodes Incorporated MOSFET N-CH 30V 7.44A 8DFN</p>	 <p>DMG4712SSS-13 Diodes Incorporated MOSFET N-CH 30V 11.2A 8SOIC</p>
 <p>DMG4800LSDQ VB DMG4800LSDQ VB</p>	 <p>DMG4800LK-13 DIODES DMG4800LK-13 DIODES</p>	 <p>DMG4800LK3 DIODES DMG4800LK3 DIODES</p>	 <p>DMG4800LSD-13 Diodes Incorporated MOSFET 2N-CH 30V 7.5A 8SO</p>

heiße Teile

Mehr

- | | | | | |
|---|---|--|---|---|
|  DMG4435SSS |  DMG4435SSS-13 |  DMG4435SSS-13-89 |  DMG4466SSS |  DMG4466SSS-13 |
|  DMG4466SSS-13-F |  DMG4466SSSL |  DMG4466SSSL-13 |  DMG4466SSSL-13-F |  DMG4468LFG |
|  DMG4468LFG-7 |  DMG4468LK3 |  DMG4468LK3-13 |  DMG4496SSS |  DMG4496SSS-13 |
|  DMG4496SSS-13-F |  DMG4496SSSQ |  DMG4511SK4-13 |  DMG4710SSS |  DMG4710SSS-13 |
|  DMG4712SSS |  DMG4712SSS-13 |  DMG4800LFG-7 |  DMG4800LK-13 |  DMG4800LK3 |
|  DMG4800LSD |  DMG4800LSD-13 |  DMG4800LSD-13-F |  DMG4800LSDQ |  DMG4812SS |
|  DMG4812SSS |  DMG4812SSS-13 |  DMG4822SSD |  DMG4822SSD-13 |  DMG4822SSDQ |
|  DMG4932LS13 |  DMG4932LSD-13 |  DMG563010R |  DMG563020R |  DMG564010R |
|  DMG564020R |  DMG5640N0R |  DMG5802LFX |  DMG5802LFX-7 |  DMG6301UDW-7 |
|  DMG6402LDM |  DMG6402LDM-7 |  DMG6402LDM-7-F |  DMG6402LVT |  DMG6402LVT-7 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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